

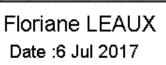
Capacitor tiles Scanning Electron Microscopy

30 µm

EHT = 20.00 kV WD = 10.2 mmAperture Size = 60.00 µm Height = 153.1 µm

Mag = 560 XWidth = 204.1 µm

Signal A = SE2 Brightness = 44.0 % Contrast = 36.9 %



Mateus Vicente

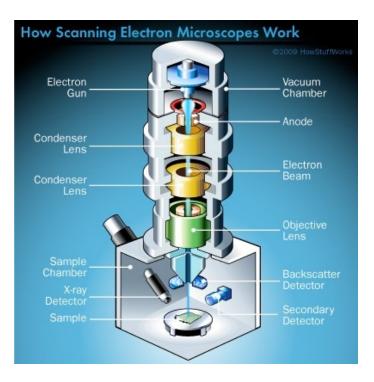


AIDA WP6.4 meeting 20/07/2017

Introduction Scanning Electron Microscopy



- Works detecting secondary electrons emitted by atoms excited by the electron beam.
 - SEM can achieve resolution better than 1 nanometer.







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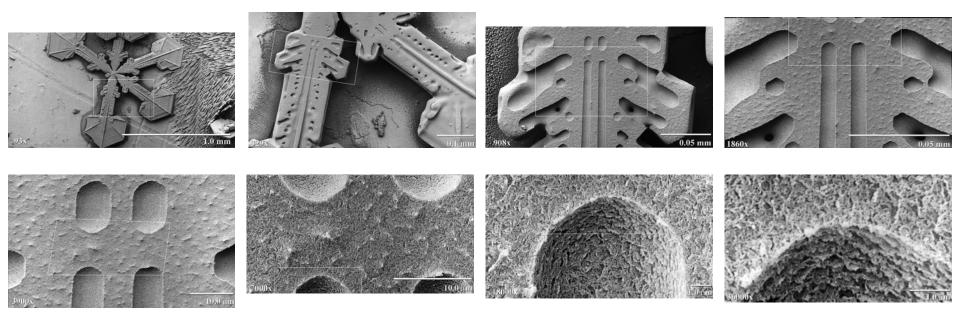
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Introduction Scanning Electron Microscopy



SEM example pictures of a snow flake (from wikipedia)









SEM Setup - CERN EN-MME-MM

 To avoid charge accumulation and image deformations, conductive carbon coating by PVD is done on the samples





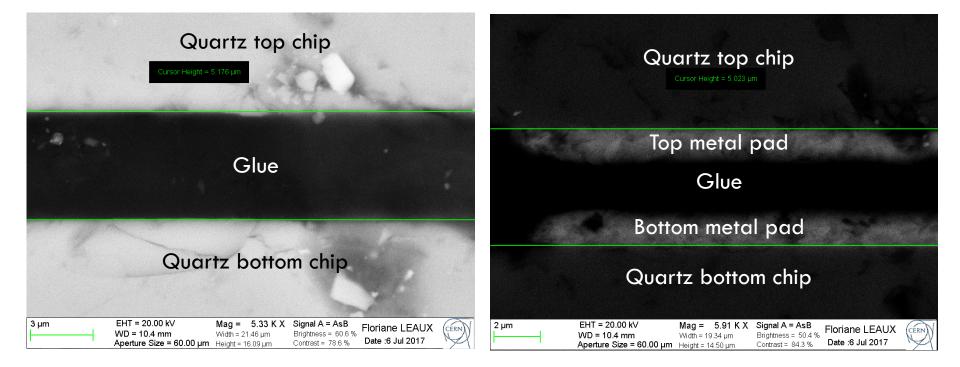


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Capacitor tile cross-section

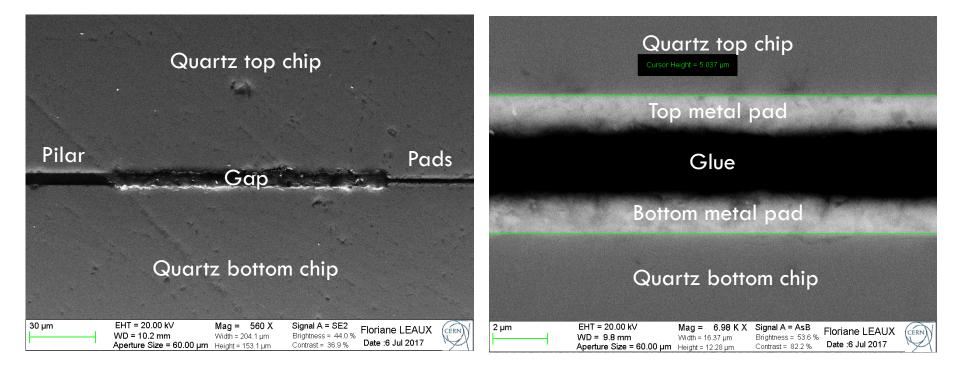








Capacitor tile cross-section





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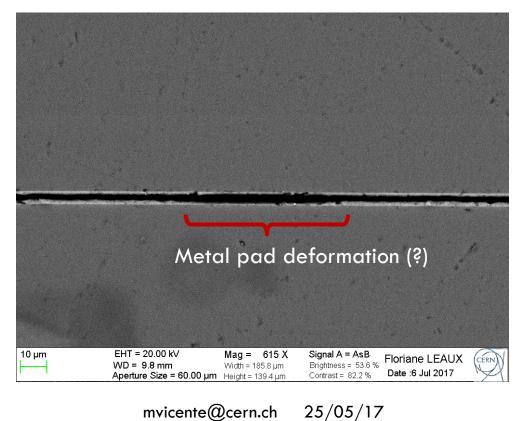
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Capacitor tile cross-section

Possible metal pad deformation (due to 10kg bonding weight(?)). To be verified.











□ Glue thickness

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- Not trivial to measure due to bad cross-section polishing
- Compare with measured capacitance and review our capacitance-gap simulation/calibration

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Investigate if (possible) air bubbles trapped between the pads have big effect on final capacitance

		Capacitance				Capacitance				
Cursor Height = 1.601 µm	3	4,15	4,03	4,06	3,97	3,87	3,96	3,87	4,13	Capacitance
The second second second	2	3,52	3,4	3,6	3,39	3,18	3,32	3,58	3,77	5
and it that the second of the	1	5,67	3,31	3,48	3,17	3	3,01	3,6	3,86	÷
	1	7,87	3,22	3,14	3,01	3,12	3,28	3,61	4,01	Č
	2	3,91	3,58	3,38	3,29	3,39	3,76	3,75	3,77	
	3	4,08	4,18	4,06	3,98	4,1	4,02	3,73	6,45	Ŭ
		123	456	789	123	123	456	789	123	
					Height	Height				
	3	3,62	3,73	3,70	3,79	3,88	3,79	3,88	3,64	5
	2	4,27	4,42	4,17	4,43	4,73	4,53	4,20	3,99	↓ ↓
	1	2,65	4,54	4,32	4,74	5,01	4,99	4,17	3,89	<u> </u>
	1	1,91	4,67	4,79	4,99	4,82	4,58	4,16	3,75	
	2	3,84	4,20	4,45	4,57	4,43	4,00	4,01	3,99	<u> </u>
EHT = 20.00 kV Mag = 8.72 K X Signal A = SE2 Floriane LEAUX	3	3,68	3,60	3,70	3,78	3,67	3,74	4,03	2,33	C
Aparture 5:26 = 60 00 µm Holio = 13.11 µm Enginness = 48.4 %		123	456	789	123	123	456	789	123	

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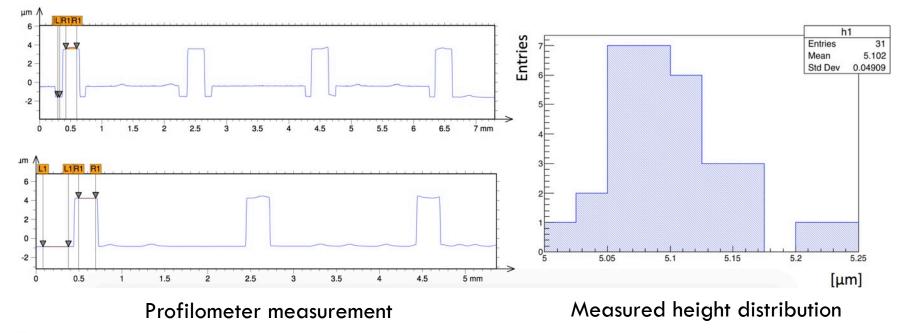




Pads gap distribution – before assembly

Height of the pillars measured with a mechanical profilometer (Genova)





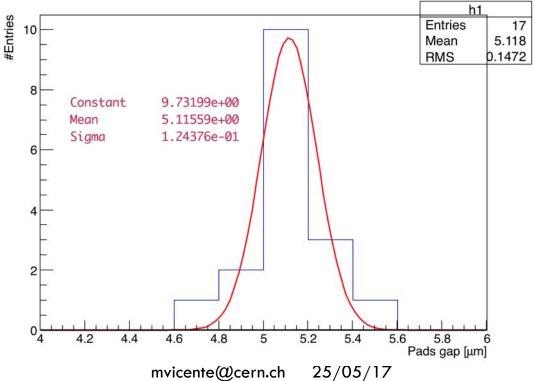


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Pads gap distribution – after assembly

- \Box Gap measurements over ~2cm cross-section (done with SEM at CERN)
 - Average gap of 5.11 um
 - Very good agreement with measurements before assembly







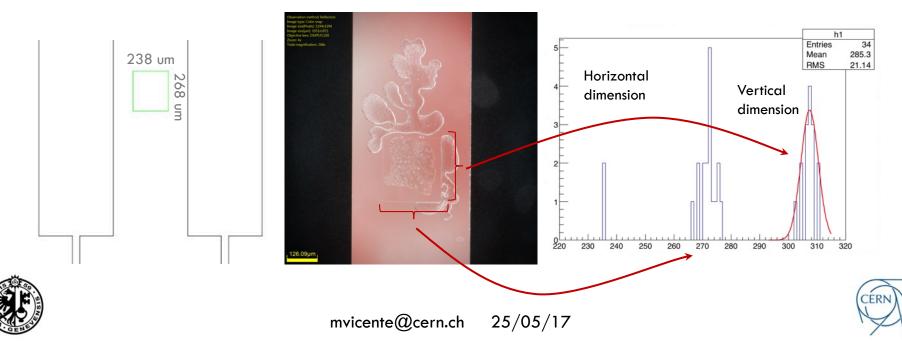


Pillar size

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Pillars of 238x268 um

- Measurement with a optical microscope
 - ~270x310 um
 - 40 um offset, probably due to light refraction through the quartz glass (to be calculated)
- With latest SEM pictures, hypothesis of pillars compression discharged







Conclusions and Next steps

- First SEM measurements performed on the capacitor tiles
 - New measurements next 24/07 of next capacitor row (2nd of 6)
 - Cross-verification on assembly parallelism
- Good* agreement of pillars height and tiles gap
 - Pillars can sustain up to 10 kg without being compressed
- New assemblies to be done with different pillar heights
- Next step: Pillars implementation on FEI4 assemblies with H35DEMO (to be confirmed)





